

Small-Signal Diode Schottky Diode

Features

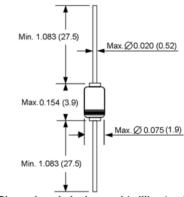
- ◆ For general purpose applications.
- These diodes feature very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- This diode is also available in the MiniMELF case with type designation LL48.



DO-204AH (DO-35 Glass)

Mechanical Data

◆ Case: DO-35 Glass Case◆ Weight: approx. 0.13g



Dimensions in inches and (millimeters)

Maximum Ratings and Thermal Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Repetitive peak reverse voltage	V _{RRM}	40	Volts
Forward continuous current at T _{amb} =25°C	Ļ	350 ⁽¹⁾	mA
Repetitive peak forward current at t_p <1s, δ <0.5, T_{amb} =25°C	I _{FRM}	1.0 (1)	Amp
Surge forward current at t _p <10ms, T _{amb} =25°C	I _{FSM}	7.5 (1)	Amps
Power dissipation (1) at T _{amb} =65°C	P _{tot}	330 (1)	mW
Thermal resistance junction to ambient air	R _{eJA}	300 (1)	°C/W
Junction temperature	T _j	125	°C
Ambient operating temperature range	T _{amb}	-65 to +125	°C
Storage temperature range	T _s	-65 to +150	°C

Notes: 1. Valid provided that leads at a distance of 4mm from case are kept at ambient temperature.

Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

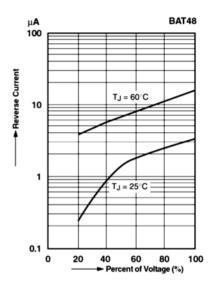
Parameter	Symbol	Min.	Тур.	Max.	Unit
Reverse breakdown voltage tested with 100uA pulses	V _{(BR)R}	40	-	-	Volts
Leakage current pulse test t <300us, δ <2% at V _R =10V, T _j =60°C at V _R =20V, T _j =60°C at V _R =20V, T _j =60°C at V _R =40V, T _j =60°C at V _R =40V, T _j =60°C	l _R	- - - - -	- - - - -	2 15 5 25 25 50	uА
Forward voltage pulse test t_s <300us, δ <2% at l_s =0.1mA at l_s =1.0mA at l_s =10mA at l_s =50mA at l_s =200mA at l_s =500mA	V _F	- - - - -	- - - - -	0.25 0.30 0.40 0.50 0.75 0.90	Volt
Capacitance at V _p =1V, f=1MHz	C _{tot}	-	12	-	pF

Notes: 1. Valid provided that leads at a distance of 4mm from case are kept at ambient temperature(DO-35)

Forward Characteristics

mA BAT48 1000 100 100 T_J = 60°C T_J = 25°C 1 0.1 0.2 0.4 0.6 0.8 VF (V)

Typical Reverse Characteristics



Admissible Power Dissipation vs. Ambient Temperature

